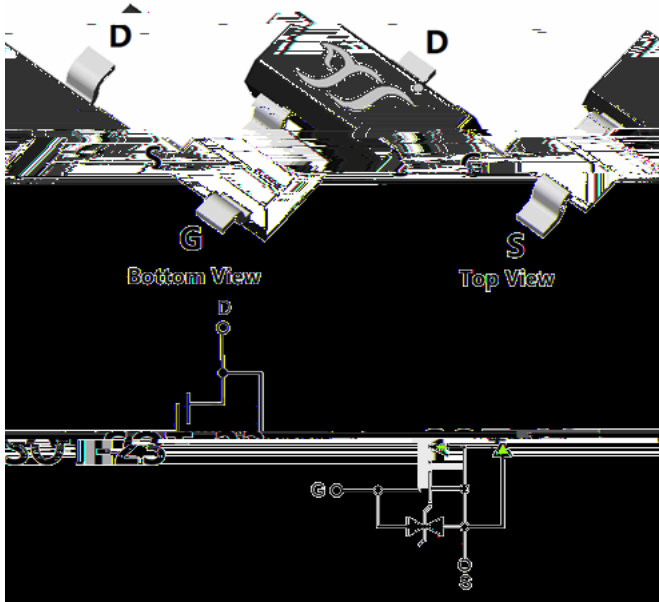




## N-Channel Enhancement Mode Field Effect Transistor



### Product Summary

$V_{DS}$	50V
$I_D$	0.22A
$R_{DS(ON)}$ ( at $V_{GS}=10V$ )	1.6
$R_{DS(ON)}$ ( at $V_{GS}=4.5V$ )	2.5
$R_{DS(ON)}$ ( at $V_{GS}=2.5V$ )	3.8
Gate-Source ESD Rating Up to 1.5KV (HBM)	

### General Description

- Excellent package for heat dissipation
- High density cell design for low  $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free
- Part no. with suffix "Q" means AEC-Q101 qualified

### Applications

- Power Management Functions
- Load switch
- DC-DC convertor

### Absolute Maximum Ratings ( $T_J=25$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	$V_{DS}$	50	V
Gate-source Voltage	$V_{GS}$	$\pm 20$	V

Continuous Drb      T      -      M      M      rent

	$c=25$ , $t_p=100\mu s$	$I_{DM}$	1	A
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Total Power Dissipation (Note 1,2)      Steady-State       $T_A=25$       R

		$J_A$	-	202	/W
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### Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
BSS138AJKQ	F2	.SS	3000	30000	120000	7" reel



# BSS138AJKQ

## Electrical Characteristics (T<sub>J</sub>=25 unless otherwise noted)

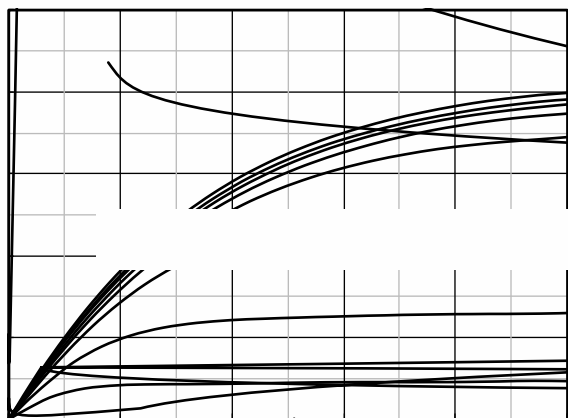
Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	50	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V	-	-	1	μA
		V <sub>DS</sub> =50V, V <sub>GS</sub> =0V, T <sub>J</sub> =150	-	-	100	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> =0V	-	-	±5	μA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =250μA	0.7	1	1.45	V
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	1.2	1.6	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.1A	-	1.24	2.5	
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =0.1A	-	1.8	3.8	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =0.22A, V <sub>GS</sub> =0V	-	-	1.2	V
Gate resistance	R <sub>G</sub>	f=1MHz	-	75	-	
Maximum Body-Diode Continuous Current	I <sub>S</sub>		-	-	0.22	A
<b>Dynamic Parameters</b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHz	-	29	-	pF
Output Capacitance	C <sub>OSS</sub>		-	4.3	-	
Reverse Transfer Capacitance	C <sub>RSS</sub>		-	3	-	
<b>Switching Parameters</b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =25V, I <sub>D</sub> =0.5A	-	1.2	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.15	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	0.31	-	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =0.5A, di/dt=100A/us	-	2.1	-	nC
Reverse Recovery Time	t <sub>rr</sub>		-	9.2	-	ns
Turn-on Delay Time	t <sub>D(on)</sub>	V <sub>GS</sub> =10V, V <sub>DD</sub> =25V, I <sub>D</sub> =0.5A R <sub>GEN</sub> =25	-	3	-	ns
Turn-on Rise Time	t <sub>r</sub>		-	2.7	-	
Turn-off Delay Time	t <sub>D(off)</sub>		-	11	-	
Turn-off fall Time	t <sub>f</sub>		-	8.1	-	

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of R<sub>JA</sub> is measured with the device mounted on the 40mm\*40mm\*1.1mm single layer FR-4 PCB board with 1 in<sup>2</sup> pad of 2oz. Copper, in the still air environment with TA =25 . The maximum allowed junction temperature of 150 . The value in any given application depends on the user's specific board design.



## Typical Electrical and Thermal Characteristics Diagrams





# BSS138AJKQ

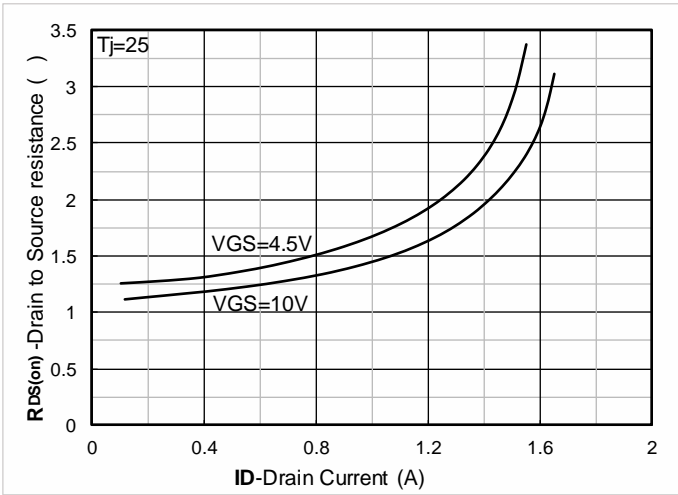


Figure 7.  $R_{DS(on)}$  VS Drain Current

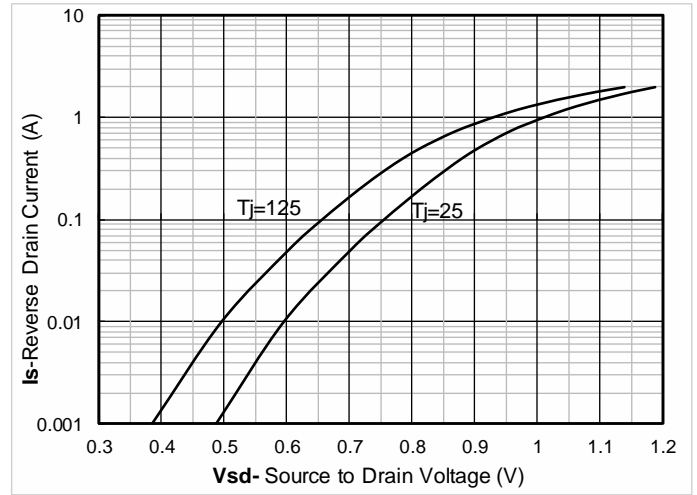
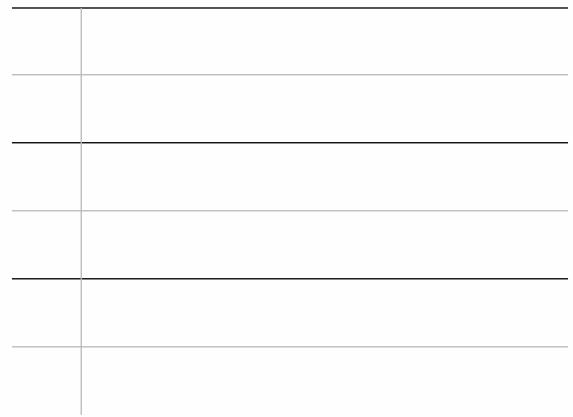
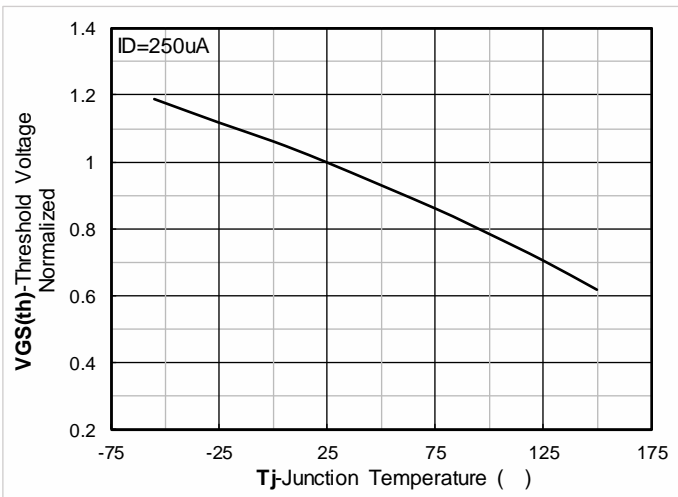


Figure 8. Forward characteristics of reverse diode

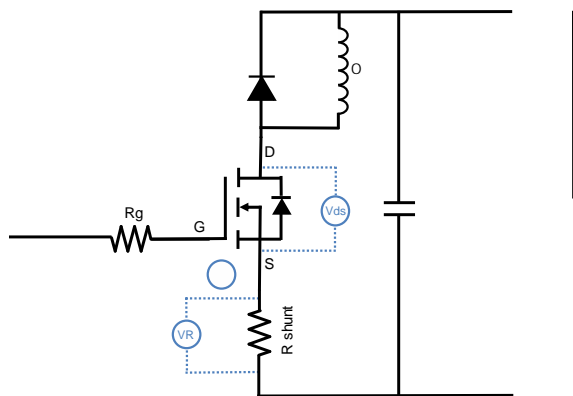


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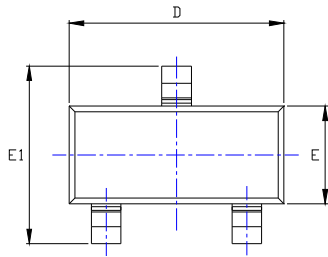
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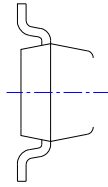


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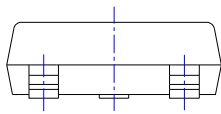
## SOT-23 Package information



TOP VIEW



SIDE VIEW



UNIT mm

SUGGESTED SOLDER PAD LAYOUT



## BSS138AJKQ

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